

# UMZ-659-A16-G

#### MICROSTRIP VOLTAGE CONTROLLED OSCILLATOR

Package: A16, 12.7mm x 12.7mm x 3.43mm

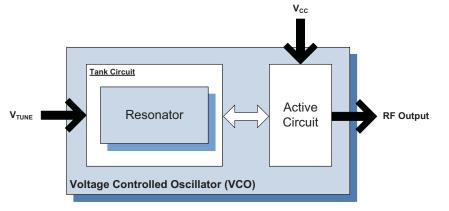


### Features

- Ultra-Linear Tuning/Low Phase Noise
- Frequency: 3190MHz to 3210MHz
- Resonator: Microstrip
- PCB: Rogers
- Package Size: 12.7mm x 12.7mm x 3.43mm (0.5in x 0.5in x 0.135in)

## Applications

- Frequency Synthesizers
- Up & Down Converters
- Instrumentation
- Wideband Frequency Applications



Functional Block Diagram

## **Product Description**

This series of VCO modules offers ultra-linear tuning across their specified frequency band.

#### **Ordering Information**

UMZ-659-A16-G Contact us at 1-480-756-6070

### **Optimum Technology Matching® Applied**

GaAs HBT
GaAs MESFET
InGaP HBT

support, contact

SiGe BiCMOS
Si BiCMOS
SiGe HBT

1) 636-678-5570 or customerspryice@rfmd

□ GaAs pHEMT □ GaN HEMT □ Si CMOS □ BiFET HBT ☑ Si BJT □ LDMOS

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#### **Absolute Maximum Ratings**

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Parameter	Rating	Unit
Operating Ambient Temperature[1]	-40 to +85	°C
Storage Temperature	-55 to +125	°C

[1] Frequency drift: 6MHz typical, 12MHz maximum (either extreme)



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

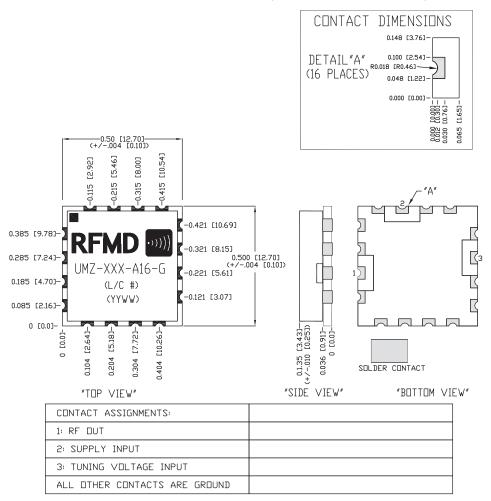
Parameter		Specification		11	
	Min.	Тур.	Max.	Unit	Condition
Overall					
Frequency Range	3190		3210	MHz	
Tuning Voltage	0.5		4.5	V <sub>DC</sub>	
Tuning Sensitivity		30		MHz/V	
Output Power	4	6	8	dBm	
	0			dBm	At V <sub>T</sub> =0
Output Phase Noise		-78	-73	dBc/Hz	1kHz
		-104	-99	dBc/Hz	10kHz
		-124	-119	dBc/Hz	100kHz
		-144	-139	dBc/Hz	1000 kHz
		-164	-159	dBc/Hz	10000kHz
Second Harmonic		-20	-15	dBc	
Frequency Pulling		2	4	MHz p-p	At 12dBr, all phases
Tuning Port Capacitance		47		pF	
Modulation Bandwidth		1000		kHz	3dB BW
Frequency Pushing		2	5	MHz/V	
Power Supply			·		
Operating Voltage		5		V	
Supply Current		27		mA	





## Package Drawing & Pin Outs

12.7mm x 12.7mm x 3.43mm (0.5in x 0.5in x 0.135in)



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